

Index Guided AlGaInP Laser Diode

Overview

DL-3149-054 is 670 nm (Typ.) index guided AlGaInP laser diode with low threshold current and high operating temperature. The low threshold current and high operating temperature are achieved by the use of a strained multiple quantum well active layer. DL-3149-054 is suitable for applications such as bar-code scanners, laser pointers and other optical information systems.

Features

· Short wavelength : 670 nm (Typ.) · High operating temperature: 60°C at 5 mW : Ith = 30 mA (Typ.) · Low threshold current · Small package : 5.6 mm ϕ

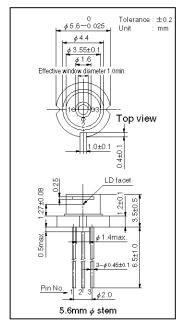
Absolute Maximum Ratings at Tc=25 $^{\circ}$ C

Parameter	Symbol	Ratings	Unit		
Light Output		Po	5	mW	
Reverse Voltage	Laser PIN	V_R	2 30	V	
Operating Temperature		Topr	-10 to +60	$^{\circ}\mathbb{C}$	
Storage Temperature		Tstg	-40 to +85	$^{\circ}\!\mathbb{C}$	

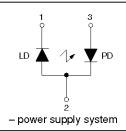
Electrical and Optical Characteristics at Tc=25 $^{\circ}$ C							– power supply system		
Para	meter	Symbol	Condition	Min.	Тур.	Max.	Unit		
Threshol	d Current	Ith	CW	_	30	5 0	mA		
Operatin	g Current	Iop	Po=5mW	-	45	60	mA		
Operatin	g Voltage	Vop	Po=5mW	_	2.3	2.6	V		
Lasing W	avelength	λp	Po=5mW	660	670	680	nm		
Beam 💥)	Perpendicular	θ⊥	Po=5mW	25	33	40	deg.		
Divergence	Parallel	θ//	Po=5mW	6	8	10	deg.		
Off Axis	Perpendicular	$\Delta heta \perp$	_	_	_	±3	deg.		
Angle	Parallel	$\Delta heta$ //	_	_	_	±3	deg.		
Differentia	l Efficiency	dPo/dIop	_	0.15	0.3	_	mW/mA		
Monitoring C	utput Current	Im	Po=5mW	0.4	1.2	2.0	mA		
Astigr	natism	As	Po=5mW	_	8	_	μm		

💥) Full angle at half maximum note: The above product specifications are subject to change without notice.

Package Dimensions

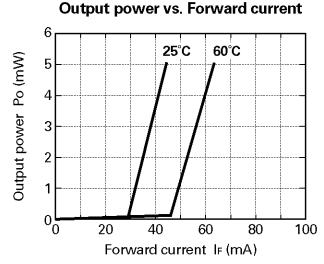


Electrical Connection

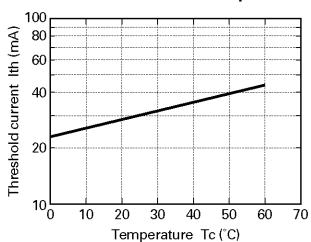


Characteristics

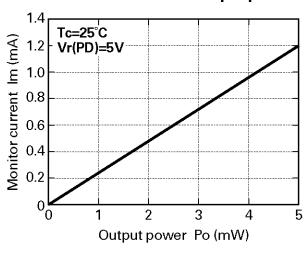




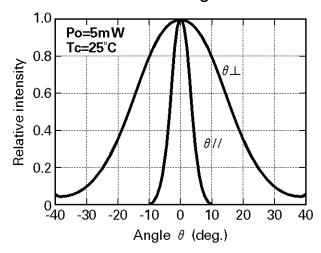
Threshold current vs. Temperature



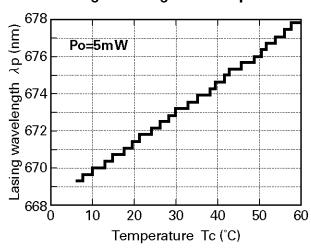
Monitor current vs. Output power



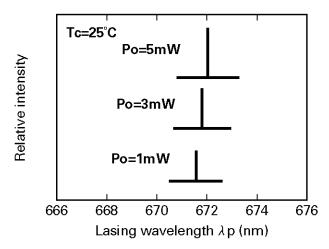
Beam divergence



Lasing wavelength vs. Temperature



Output power vs. Lasing wavelength





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Precautionary instructions in handling gallium arsenic products

Special precautions must be taken in handling this product because it contains, gallium arsenic, which is designated as a toxic substance by law. Be sure to adhere strictly to all applicable laws and regulations enacted for this substance, particularly when it comes to disposal.

Manufactured by; Tottori SANYO Electric Co., Ltd.

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